

LSIC2SD120C10









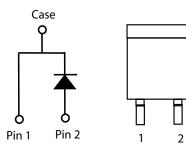
Description

This series of silicon carbide (SiC) Schottky diodes has negligible reverse recovery current, high surge capability, and a maximum operating junction temperature of 175 °C. These diodes series are ideal for applications where improvements in efficiency, reliability, and thermal management are desired.

Features

- Positive temperature coefficient for safe operation and ease of paralleling
- 175 °C maximum operating junction temperature
- Excellent surge capability
- Extremely fast, temperature-independent switching behavior
- Dramatically reduced switching losses compared to Si bipolar diodes

Circuit Diagram TO-252-2L (DPAK)



Applications

- Boost diodes in PFC or DC/DC stages
- Switch-mode power supplies
- Uninterruptible power supplies
- Solar inverters
- Industrial motor drives
- EV charging stations

Environmental

- Littelfuse "RoHS" logo = RoHS RoHS conform
- Littelfuse "HF" logo = **HF**Halogen Free
- Littelfuse "PB-free" logo = PB-free lead plating

Maximum Ratings

Characteristics	Symbol	Conditions	Value	Unit	
Repetitive Peak Reverse Voltage	V _{RRM}	-	1200	V	
DC Blocking Voltage	V _R	T _j = 25 °C	1200	V	
		T _C = 25 °C	33	А	
Continuous Forward Current	l _F	T _C = 135 °C	16		
		T _C = 156 °C	10		
Non-Repetitive Forward Surge Current	I _{FSM}	$T_c = 25 \text{ °C}, T_p = 10 \text{ ms}, \text{ Half sine pulse}$	80	А	
Power Dissipation	D	T _c = 25 °C	176	W	
	P _{Tot}	T _C = 110 °C	76	VV	
Operating Junction Temperature	T _J	-	-55 to 175	°C	
Storage Temperature	T _{STG}	-	-55 to 150	°C	
Soldering Temperature	T _{sold}	-	260	°C	

GEN2 SiC Schottky Diode LSIC2SD120C10, 1200 V, 10 A, TO-252-2L (DPAK)

Electrical Characteristics

			Value				
Characteristics S	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Forward Voltage	V _F	I _F = 10 A, Τ _J = 25 °C	-	1.5	1.8	V	
		I _F = 10 A, T _J = 175 °C	-	2.2		V	
Reverse Current	I _R	$V_{R} = 1200 \text{V}, T_{J} = 25 ^{\circ}\text{C}$	-	<1	100	μΑ	
		V _B = 1200 V , T _J = 175 °C	-	10			
Total Capacitance	С	V _R = 1 V, f =1 MHz	-	582		pF	
		V _R = 400 V, f = 1 MHz	-	53			
		V _R = 800 V, f = 1 MHz	-	40			
Total Capacitive Charge	O _C	$V_{R} = 800 \text{ V}, \ Q_{C} = \int_{0}^{V_{R}} c(v)dv$	-	57		nC	

Footnote: T₁ = +25 °C unless otherwise specified

Thermal Characteristics

Characteristics Sy		2	Value			
	Symbol	Conditions	Min.	Тур.	Max.	Unit
Thermal Resistance	R _{euc}	-	-	0.85		°C/W

Figure 1: Typical Foward Characteristics

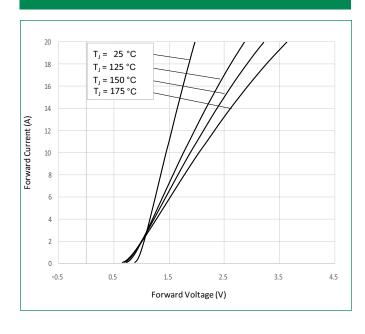


Figure 2: Typical Reverse Characteristics

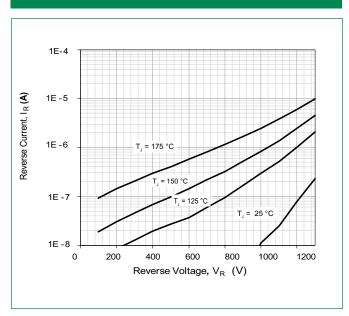




Figure 3: Power Derating

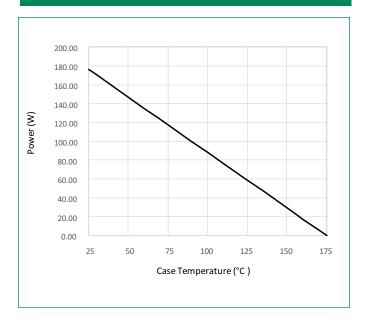


Figure 4: Current Derating

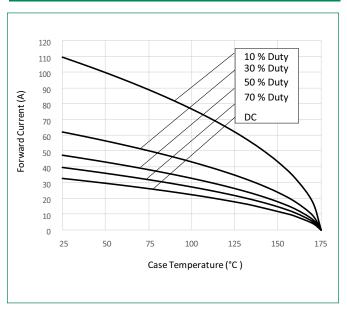


Figure 5: Capacitance vs. Reverse Voltage

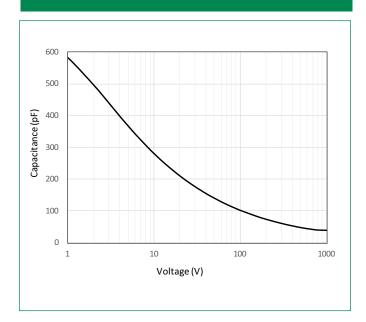
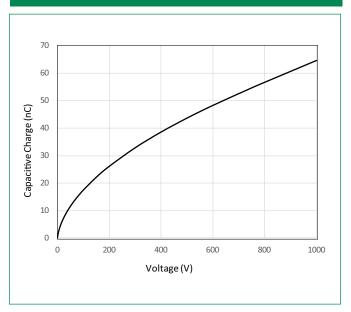


Figure 6: Capacitive Charge vs. Reverse Voltage



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Figure 7: Stored Energy vs. Reverse Voltage

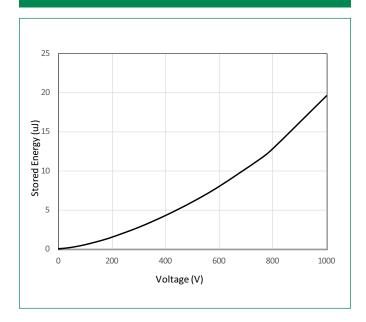
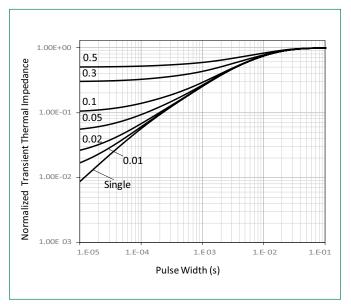
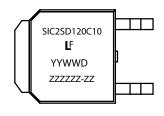


Figure 8: Transient Thermal Impedance



Part Numbering and Marking System



SIC	= SiC Diode
2	= Gen2
SD	= Schottky Diode
120	= Voltage Rating (1200 V)
С	= TO-252-2L (DPAK)
10	= Current Rating (10 A)
YY	= Year
WW	= Week

ZZZZZZ-ZZ = Lot Number

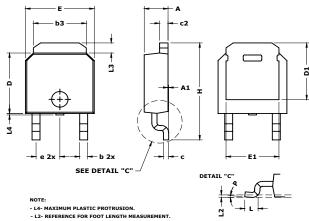
= Special code (fixed)

Packing Options

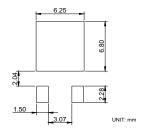
Part Number	Part Number Marking		M.O.Q
LSIC2SD120C10	SIC2SD120C10	Tape and Reel	2500



Dimensions TO-252-2L (DPAK)

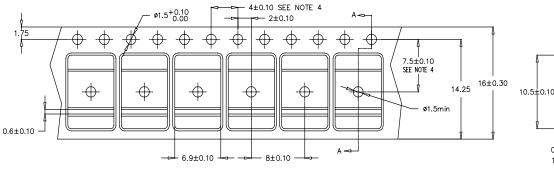


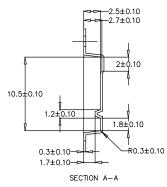
Recommended Solder Pattern Layout



Symbol	Inches			Millimeters		
Cymbol	Min	Nom	Max	Min	Nom	Max
Α	0.085	0.090	0.095	2.16	2.29	2.41
A1	0	0.003	0.005	0	0.08	0.13
b	0.025	0.030	0.035	0.64	0.76	0.89
b3	0.195	0.200	0.215	4.95	5.08	5.46
С	0.018	0.020	0.024	0.46	0.51	0.61
C2	0.018	0.032	0.035	0.46	0.81	0.89
D	0.235	0.240	0.245	5.97	6.10	6.22
D1	0.205	-	-	5.21	-	-
Е	0.250	0.260	0.265	6.35	6.60	6.73
E1	0.170	-	-	4.32	-	-
е	0.090 BSC			2.29 BSC		
Н	0.370	0.387	0.410	9.40	9.83	10.41
L	0.040	0.045	0.050	1.02	1.14	1.27
L2	0.010 BSC			0.25 BSC		
L3	0.035	-	0.050	0.89	-	1.27
L4	0	-	0.006	0	-	0.15
Р	0°	-	8°	0°	-	8°

Carrier Tape & Reel Specification TO-252-2L (DPAK)





- Material: Black Conductive Polysterene
 10 sprocket hole pitch cumulative tolerance ± 0.20
 3. Camber not to exceed 1 mm in 100 mm.
 4 Pocket position relative to sprocket hole measured as true position of pocket, not pocket hole.
 5. Device orientation: TRL (leads perpendicular to the sprocket)

- 6. General tolerance is \pm 0.10 mm unless otherwise specified.

COVER TAPE SPECS:

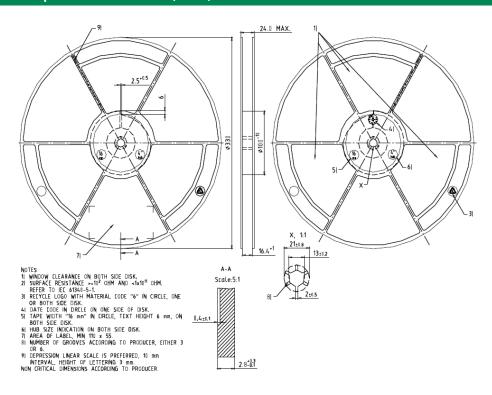
Width : 13.5 mm

: less than 1.2x10¹² ohms/square Base Material Transparent polyester, static dissipative : Polyethylene Adhesive Laver

Total Thickness : 60 Micron Tensile Strength : 4-6 kg/mm² : 91% Elongation Tearing Strength : 11 kg/mm² : 2 years Shelf life

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SS3003CH-TL-E GA01SHT18 CRS10I30A(TE85L,QM MA4E2501L-1290 MBRB30H30CT-1G SB007-03C-TB-E SK32A-TP SK33B-TP
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